

Application No. 10/695,302

**Amendments to the claims**

This listing of claims will replace all prior versions and listings of claims in the application.

**Listing of Claims:**

1-15. (Canceled)

16. (Original) A method of manufacturing a printed circuit board, comprising:  
preparing a dielectric substrate of a pre-preg formed by impregnating a glass cloth or a glass nonwoven fabric with a thermosetting epoxy resin mixed with fine particles,  
coating both surfaces of the dielectric substrate with mold-releasing films and subsequently forming a via hole,  
filling in the via hole with a conductor containing a conductive filler having an average particle diameter larger than an average diameter of the fine particles,  
peeling the mold-releasing films and layering metal foils on the surfaces of the dielectric substrate,  
compressing the dielectric substrate having the metal foils by applying heat and pressure in order to adhere the dielectric substrate and the metal foils and to connect electrically the metal foils with each other, and  
forming the metal foils to have a predetermined pattern.

17. (Original) The method of manufacturing a printed circuit board according to claim 16, wherein the resin layers on the surfaces of the pre-preg have a thickness ranging from 5  $\mu\text{m}$  to 25  $\mu\text{m}$ .

18. (Original) The method of manufacturing a printed circuit board according to claim 16, wherein the dielectric substrate in a pre-preg stage comprises a void.

Application No. 10/695,302

19. (Original) The method of manufacturing a printed circuit board according to claim 16, wherein the void has a diameter smaller than a diameter of the conductive filler in the conductor.
20. (Original) The method of manufacturing a printed circuit board according to claim 16, wherein the dielectric material is thinned by applying heat and pressure.
21. (Original) The method of manufacturing a printed circuit board according to claim 16, wherein the conductor filled in the via hole formed in the thickness direction of the dielectric substrate is thinned by applying heat and pressure.
22. (Original) The method of manufacturing a printed circuit board according to claim 16, wherein the dielectric substrate has a substantially uniform thickness in the center and in the periphery after application of heat and pressure.
23. (Currently Amended) The method of manufacturing a printed circuit board according to claim [[,]] 16, further comprising:
- filling a conductor in a dielectric substrate composed of a pre-preg of a glass cloth or a glass nonwoven fabric impregnated with a thermosetting epoxy resin mixed with fine particles,
  - layering the dielectric substrate and metal foils onto both surfaces of a printed circuit board prepared in accordance with claim 16,
  - compressing the printed circuit board by applying heat and pressure so as to embed wiring layers of the printed circuit board in the resin layers on the surfaces of the dielectric substrate, and
  - forming the metal foils to have a predetermined pattern.
24. (Original) The method of manufacturing a printed circuit board according to claim 16, comprising:
- forming a plurality of double-sided printed circuit boards according to claim 16,

Application No. 10/695,302

filling a conductor in a dielectric substrate composed of a pre-preg of a glass cloth or a glass nonwoven fabric impregnated with a thermosetting epoxy resin mixed with fine particles,

layering the dielectric substrate between the double-sided printed circuit boards, compressing the printed circuit board by applying heat and pressure so as to embed the wiring layers of the double-sided printed circuit board in the resin layers on the surface of the dielectric substrate,

with all the conductors having substantially same thickness.

25-26. (Canceled)

27. (New) The method of manufacturing a printed circuit board according to claim 16, wherein at least one inorganic filler selected from powders of  $\text{SiO}_2$ ,  $\text{TiO}_2$ ,  $\text{Al}_2\text{O}_3$ ,  $\text{MgO}$ ,  $\text{SiC}$  and  $\text{AlN}$  is added to the glass epoxy resin dielectric substrates in a pre-preg stage and a content of the inorganic filler ranges from 30 wt% to 70 wt% to the entire epoxy resin.